



Colloquium Notice

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Graphene Nanophotonics and Nanoelectronics

Graphene, a 2-dimensional carbon based material system, recently attracts world-wide attention from physicists and engineers due to its unique electronic and photonic properties. In this talk, I will first discuss the historical evolution of electronics and photonics, followed by the potential of graphene in electronics and photonics. A few important developments in graphene photonics will then be presented, including photocurrent imaging, ultrafast (> 40 GHz) photoresponse, and the application of graphene photodetector in a realistic optical communication link. Next, two approaches to create a bandgap, using lateral confinement in single layer graphene and vertical E-field in bi-layer graphene, will be covered in detail. I will show that a transport bandgap of > 130 meV can be realized in biased bilayer graphene. The developments in graphene bandgap engineering may enable a few important applications, such as graphene digital electronics, electron Veselago lens and graphene spin qubit

Monday

October 18, 2010

Starts at 12:15 PM

Coffee at 12:00 PM

Physics Conference Room, SB B326